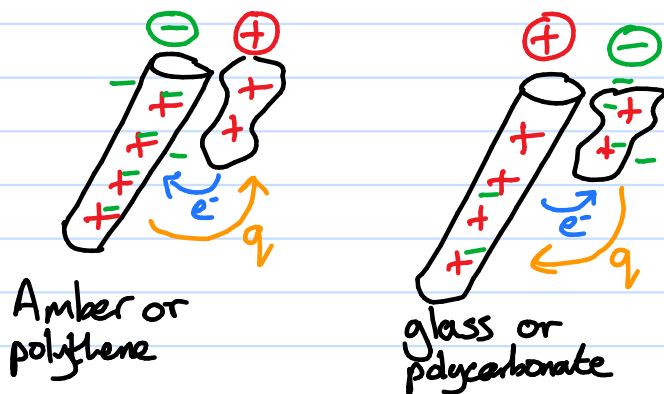


Current and charge

electrons $q_e = -1.60 \times 10^{-19} \text{ C} = -e$
protons $q_p = 1.60 \times 10^{-19} \text{ C} = e$

Current $I = \frac{\Delta Q}{\Delta t} = \frac{dQ}{dt} \rightarrow \int I(t) dt = Q$

Rate of flow of charge = current

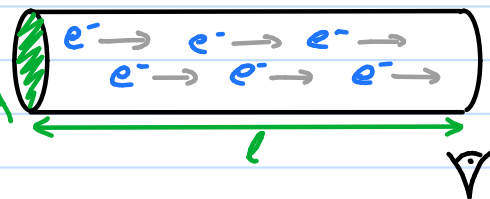


- Like charges
- unlike charges attract

Current flows in opposite direction to electrons

Drift velocity

Cross sectional area A



n = electron density = 10^{29} m^{-3}
 N = number of electrons
 V = volume = Al
 I = current

$$I = \frac{Q}{t} = \frac{Ne}{t} = \frac{nVe}{t} = \frac{nAle}{t} = nAve$$

$$\text{drift velocity } v = \frac{I}{nAe} = \frac{4I}{\pi nd^2 e}$$

$(A = \frac{1}{4}\pi d^2 \text{ for a cylinder})$

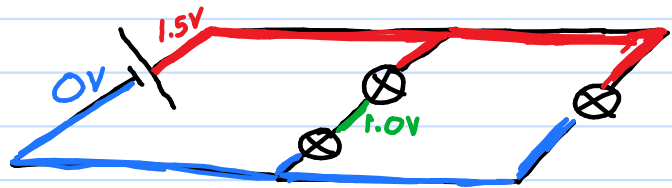
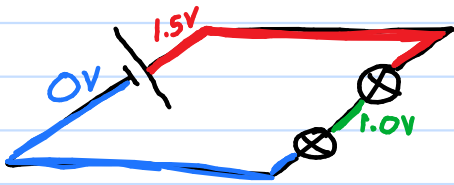
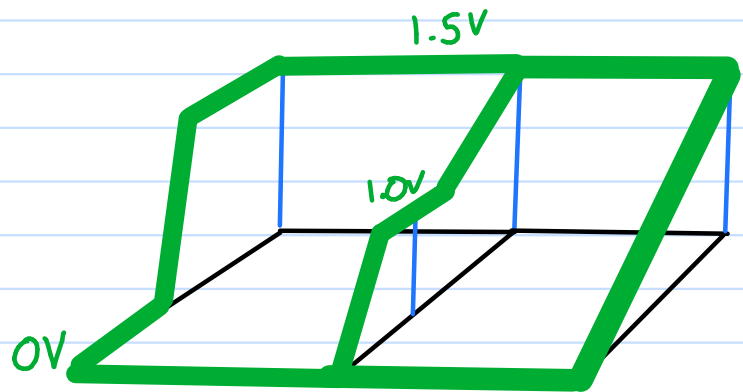
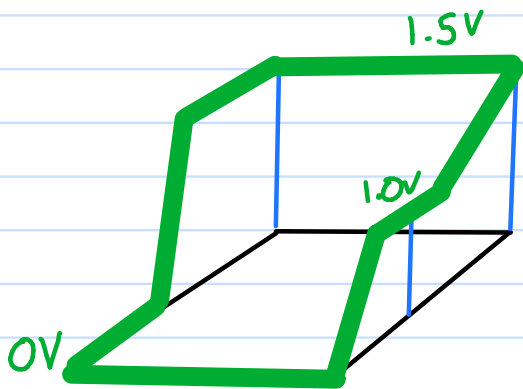
For a typical circuit $I = 0.50 \text{ A}$, $n = 10^{29} \text{ m}^{-3}$, $d = 1.0 \text{ mm}$
 $e = 1.60 \times 10^{-19} \text{ C}$

$$v = \frac{4 \times 0.50}{\pi \times 10^{29} \times (1.0 \times 10^{-3})^2 \times 1.60 \times 10^{-19}} = 4.0 \times 10^{-5} \text{ ms}^{-1} \\ = 4.0 \times 10^{-2} \text{ mm s}^{-1} \\ = 40 \text{ } \mu\text{m s}^{-1}$$

- Conductors - charge can easily flow
- Insulators - charge cannot easily flow
- Semiconductors - more current under certain circumstances.

Potential difference and power

$$\text{potential difference} = \text{voltage} = \frac{W}{Q}$$



Power

$$P = \frac{W}{t}$$

$$W = QV$$

$$Q = It$$

$$W = IVt$$

$$P = \frac{IV\cancel{t}}{\cancel{t}} = IV$$

Resistance $R = \frac{V}{I}$ measured in ohms Ω

Prefixes

nano	micro	milli	kilo	mega	giga
n	μ	m	k	M	G
10^{-9}	10^{-6}	10^{-3}	10^3	10^6	10^9

$V = IR$ is not Ohm's law; Ohm's law is that, for Ohmic components, R does not depend on I (i.e. is constant) at a given temperature. $V \propto I$ at constant temperature

Resistivity

the longer the wire, the greater the resistance } $R \propto \frac{L}{A}$
the thinner the wire, the greater the resistance } $\leftarrow$ length
 $\leftarrow$ cross sectional area

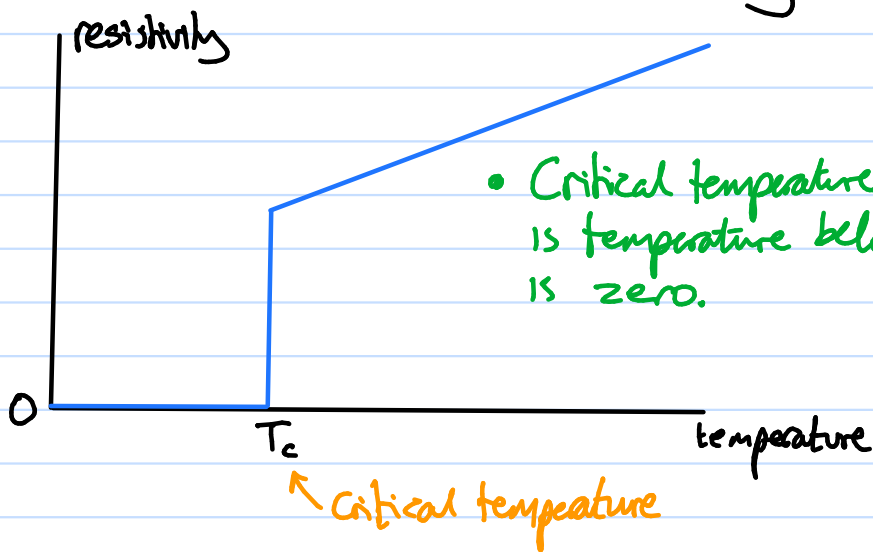
$$R = \rho \frac{L}{A}$$

ρ resistivity

$$\rho = \frac{RA}{L} \quad \text{units: } \frac{\Omega \text{ m}^2}{\text{m}} = \Omega \text{ m}$$

Superconductivity

As temperature of metal reduced, resistivity reduces



Components and their characteristics

 cell

 diode

 voltmeter

 lamp

 light emitting diode LED

 ammeter

 fixed resistor

 light dependent resistor

 oscilloscope

 variable resistor

 heater

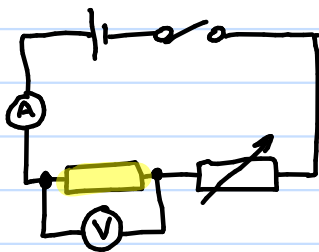
 terminal

 thermistor

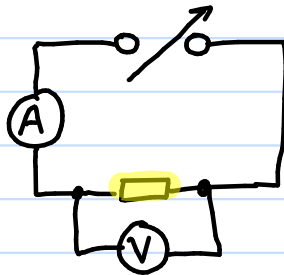
 motor

 switch

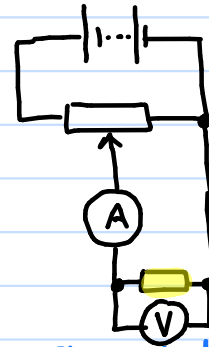
Measuring component characteristics



using variable resistor

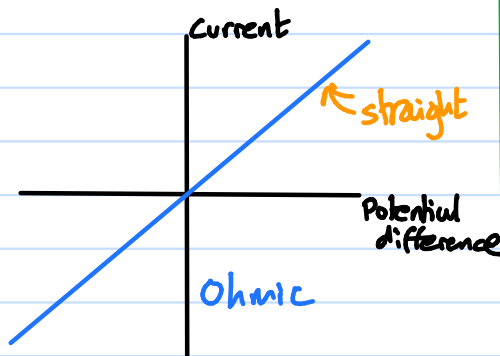


using variable power supply

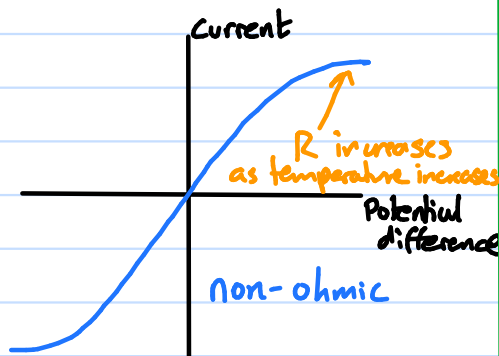


using potentiometer

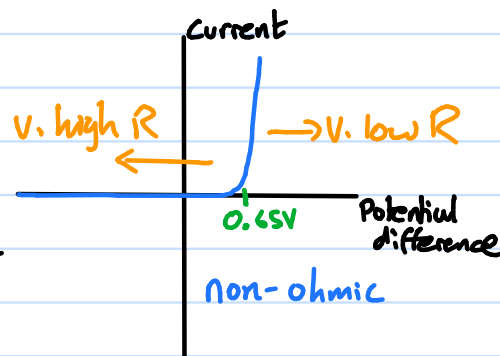
For a fixed resistor:



For a filament lamp:



For a diode:



Resistance and temperature

